

# 40V +175°C N-CHANNEL ENHANCEMENT MODE MOSFET POWERDI®

### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> T <sub>C</sub> = +25°C (Note 10)
40V	$3.7$ m $\Omega$ @ V <sub>GS</sub> = 10V	100A

#### **Features**

- Rated to +175°C Ideal For High Ambient Temperature Environments
- 100% Unclamped Inductive Switching Ensures More Reliable And Robust End Application
- Low R<sub>DS(ON)</sub> Minimizes Power Losses
- Low Q<sub>a</sub> Minimizes Switching Losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

### **Description and Applications**

This MOSFET is designed to meet the stringent requirements of Automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

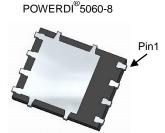
- Engine Management Systems
- Body Control Electronics
- DC-DC Converters

#### **Mechanical Data**

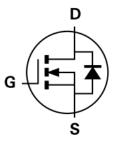
- Case: POWERDI<sup>®</sup>5060-8
- Case Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe.
   Solderable per MIL-STD-202, Method 208 (23)
- Weight: 0.097 grams (Approximate)



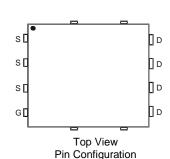




**Bottom View** 



Internal Schematic



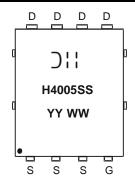
#### Ordering Information (Note 5)

Part Number	Case	Packaging	
DMTH4005SPSQ-13	POWERDI <sup>®</sup> 5060-8	2,500 /Tape & Reel	

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- Automotive products are AEC-Q101 qualified and are PPAP capable. For more information, please refer to http://www.diodes.com/product compliance definitions.html.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

#### **Marking Information**



⊃¦¦ = Manufacturer's Marking
 H4005SS = Product Type Marking Code
 YYWW = Date Code Marking
 YY = Year (ex: 14 = 2014)
 WW = Week (01 to 53)

POWERDI is a registered trademark of Diodes Incorporated.



## **Maximum Ratings** ( $@T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		$V_{DSS}$	40	V
Gate-Source Voltage		$V_{GSS}$	±20	V
Continuous Drain Current (Note 6)	$T_A = +25$ °C $T_A = +70$ °C	I <sub>D</sub>	20.9 17.5	А
Continuous Drain Current (Notes 7 & 10) $T_C = +25^{\circ}C$ $T_C = +100^{\circ}C$		I <sub>D</sub>	100 100	А
Maximum Continuous Body Diode Forward Current (Note 7)		I <sub>S</sub>	100	Α
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I <sub>DM</sub>	150	Α
Avalanche Current, L=0.6mH		I <sub>AS</sub>	21	Α
Avalanche Energy, L=0.6mH		E <sub>AS</sub>	132.3	mJ

#### **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 6)	T <sub>A</sub> = +25°C	$P_{D}$	2.6	W
Thermal Resistance, Junction to Ambient (Note 6)		$R_{\theta JA}$	57	°C/W
Total Power Dissipation (Note 7)	$T_C = +25^{\circ}C$	$P_{D}$	150	W
Thermal Resistance, Junction to Case (Note 7)		R <sub>0</sub> JC	1	°C/W
Operating and Storage Temperature Range		T <sub>J,</sub> T <sub>STG</sub>	-55 to +175	°C

## **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

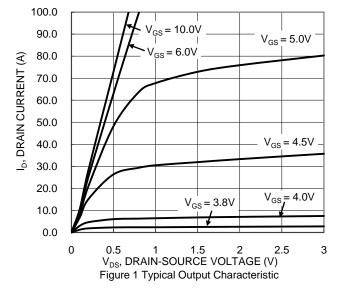
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)				•			
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	40			V	$V_{GS} = 0V$ , $I_D = 1mA$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>			1	μA	$V_{DS} = 32V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>			±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	2		4	V	$V_{DS} = V_{GS}$ , $I_D = 250\mu A$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>		2.9	3.7	mΩ	$V_{GS} = 10V, I_D = 50A$	
Diode Forward Voltage	V <sub>SD</sub>		0.88		V	$V_{GS} = 0V, I_{S} = 50A$	
DYNAMIC CHARACTERISTICS (Note 9)						•	
Input Capacitance	C <sub>iss</sub>		3,062		pF	$V_{DS} = 20V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Output Capacitance	C <sub>oss</sub>		902.2				
Reverse Transfer Capacitance	C <sub>rss</sub>		179.2				
Gate Resistance	Rg		0.67		Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge	Qg		49.1				
Gate-Source Charge	Q <sub>gs</sub>		10.3		nC	$V_{DD} = 20V, I_D = 50A,$ $V_{GS} = 10V$	
Gate-Drain Charge	Q <sub>gd</sub>		13				
Turn-On Delay Time	t <sub>D(ON)</sub>		8.7			$V_{DD} = 20V, V_{GS} = 10V,$ $I_{D} = 50A, R_{G} = 3\Omega$	
Turn-On Rise Time	t <sub>R</sub>		6.8				
Turn-Off Delay Time	t <sub>D(OFF)</sub>		18.6		ns		
Turn-Off Fall Time	t <sub>F</sub>		7.3				
Body Diode Reverse Recovery Time	t <sub>RR</sub>	_	31.8		ns	I 504 4:/4+ 4004/	
Body Diode Reverse Recovery Charge	$Q_{RR}$		26.5		nC	$I_F = 50A$ , di/dt = 100A/ $\mu$ s	

Notes:

- 6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.
  7. Thermal resistance from junction to soldering point (on the exposed drain pad).
  8. Short duration pulse test used to minimize self-heating effect.
  9. Guaranteed by design. Not subject to product testing.
  10. Package limited.







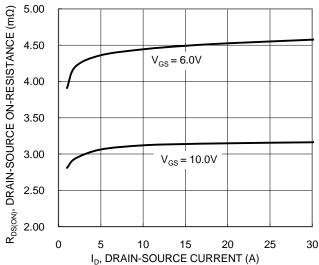


Figure 3 Typical On-Resistance vs. Drain Current and Gate Voltage

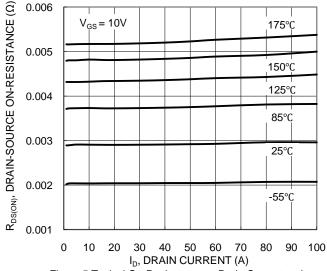
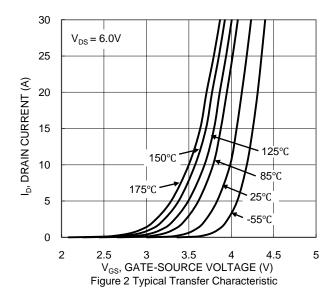
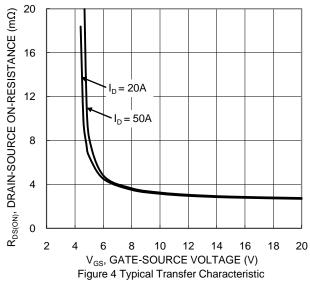


Figure 5 Typical On-Resistance vs. Drain Current and Temperature





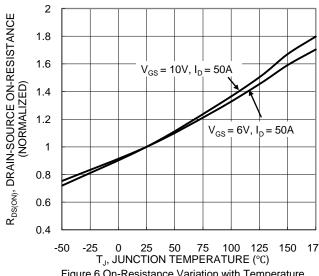


Figure 6 On-Resistance Variation with Temperature





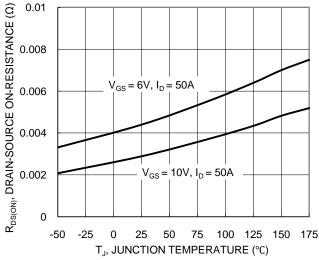


Figure 7 On-Resistance Variation with Temperature

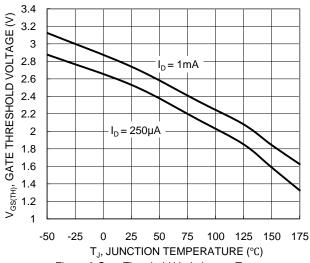
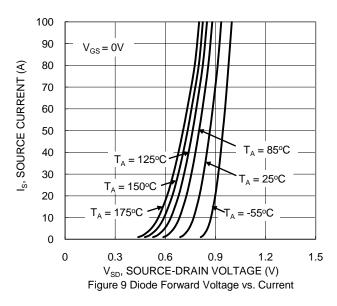
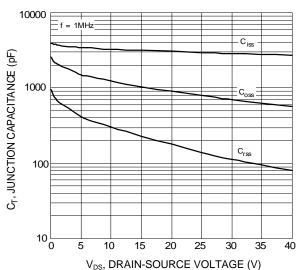


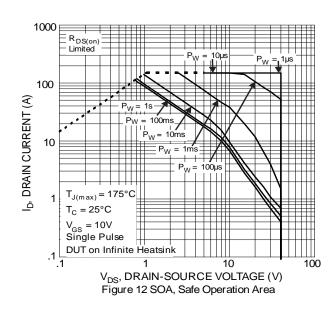
Figure 8 Gate Threshold Variation vs. Temperature



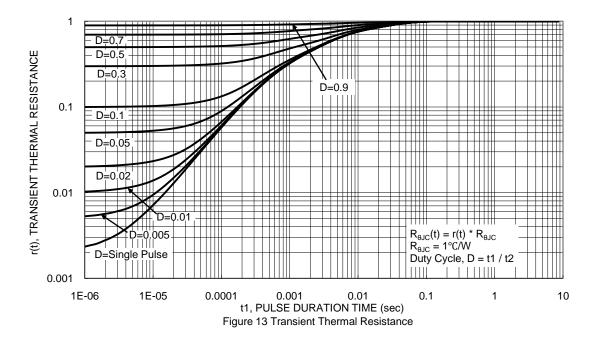
10 | S | 8 | V<sub>DS</sub> = 20V | I<sub>D</sub> = 50A | V<sub>DS</sub> = 50A | V<sub>DS</sub>



 $V_{\text{DS}}$ , DRAIN-SOURCE VOLTAGE (V) Figure 10 Typical Junction Capacitance





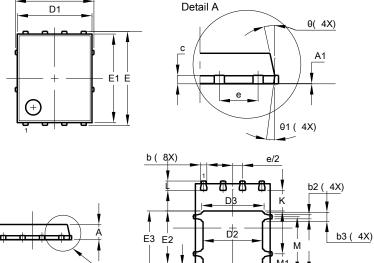




#### **Package Outline Dimensions**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

#### D Detail A D1



POWERDI®5060-8						
Dim	Min	Тур				
Α	0.90	1.10	1.00			
A1	0.00	0.05	_			
b	0.33	0.51	0.41			
b2	0.200	0.350	0.273			
b3	0.40	0.80	0.60			
С	0.230	0.330	0.277			
D	,	5.15 BSC	;			
D1	4.70	5.10	4.90			
D2	3.70	4.10	3.90			
D3	3.90					
Е	6.15 BSC					
E1	5.60	6.00	5.80			
E2	3.28	3.68	3.48			
E3	3.99	4.39	4.19			
е	1.27 BSC					
G	0.51	0.71	0.61			
K	0.51	_	_			
L	0.51	0.71	0.61			
L1	0.100	0.200	0.175			
М	3.235	4.035	3.635			
M1	1.00	1.40	1.21			
Θ	10°	12º	11º			
Θ1	6º	8º	7º			
All Dimensions in mm						

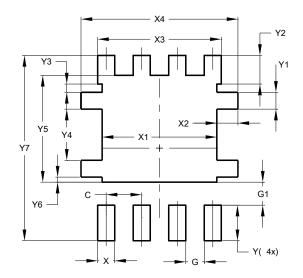
## **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

Detail A

#### POWERDI®5060-8

POWERDI®5060-8



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
Х3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610



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